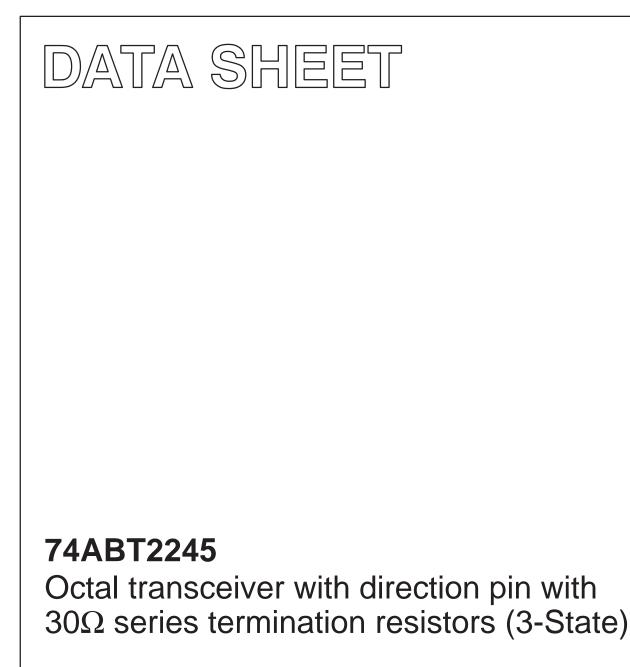
INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Sep 10 IC23 Data Handbook

1998 Jan 16



74ABT2245

FEATURES

- Octal bidirectional bus interface
- 3-State buffers
- Output capability: +12mA/-32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000 V per MIL STD 833 Method 3015 and 200 V per Machine Model
- Power-up 3-State
- Live insertion/extraction permitted
- Same as 74ABT245-1
- Outputs include series resistance of 30Ω, making external termination resistors unnecessary
- Inputs are disabled during 3-State mode

DESCRIPTION

The 74ABT2245 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed.

The 74ABT2245 device is an octal transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an Output Enable (\overline{OE}) input for easy cascading and a Direction (DIR) input for direction control.

The 74ABT2245 is designed with 30Ω series resistance in both the High and Low states of the output. This design reduces line noise in applications such as memory address drivers, clock drivers, and bus receivers/transmitters.

The 74ABT2245 is the same as the 74ABT245-1. The part number has been changed to reflect industry standards.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	C _L = 50pF; V _{CC} = 5V	3.9	ns
C _{IN}	Input capacitance DIR, OE	$V_I = 0V \text{ or } V_{CC}$	4	pF
C _{I/O}	I/O pin capacitance	Outputs disabled; $V_O = 0V$ or V_{CC}	7	pF
I _{CCZ}	Total supply current	Outputs disabled; V_{CC} =5.5V	50	μΑ

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic DIP	–40°C to +85°C	74ABT2245 N	74ABT2245 N	SOT146-1
20-Pin plastic SO	–40°C to +85°C	74ABT2245 D	74ABT2245 D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +85°C	74ABT2245 DB	74ABT2245 DB	SOT339-1
20-Pin Plastic TSSOP Type I	–40°C to +85°C	74ABT2245 PW	7ABT2245PW DH	SOT360-1

PIN CONFIGURATION

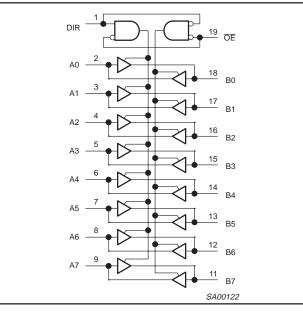
DIR 1	20	V _{CC}
A0 2	19	OE
A1 3	18	B0
A2 4	17	B1
A3 5	16	B2
A4 6	15	B3
A5 7	14	B4
A6 8	13	B5
A7 9	12	B6
GND 10	11	B7
	SA001	21

PIN DESCRIPTION

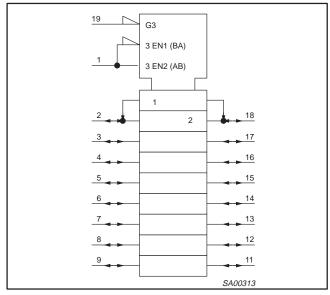
PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	DIR	Direction control input
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	ŌĒ	Output enable input (active-Low)
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

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LOGIC SYMBOL



LOGIC SYMBOL IEEE/IEC



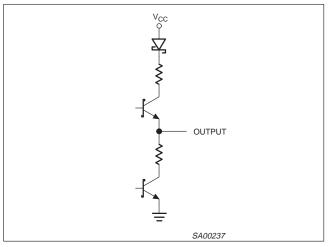
FUNCTION TABLE

INP	UTS	INPUTS/OUTPUTS			
OE	DIR	An	Bn		
L	L	An = Bn	Inputs		
L	Н	Inputs	Bn = An		
Н	Х	Z	Z		

H = High voltage level L = Low voltage level

X = Don't care Z = High impedance "off" state

SCHEMATIC OF EACH OUTPUT



74ABT2245

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V ₁ < 0	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
I _{ОК}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
I _{OUT}	DC output current	output in Low state	128	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
		Min	Max	1
V _{CC}	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V _{CC}	V
VIH	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		12	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	5	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

Product specification

74ABT2245

DC ELECTRICAL CHARACTERISTICS

						LIMITS			
SYMBOL	PARAMETER		TEST CONDITIONS	T _{amb} = +25°C			T _{amb} = −40°C to +85°C		
				Min	Тур	Мах	Min	Max	
V _{IK}	Input clamp volt	tage	V _{CC} = 4.5V; I _{IK} = -18mA		-0.9	-1.2		-1.2	V
			V_{CC} = 4.5V; I_{OH} = -3mA; V_I = V_{IL} or V_{IH}	2.5	2.9		2.5		V
V _{OH}	High-level output	ut voltage	V_{CC} = 5.0V; I_{OH} = -3mA; V_I = V_{IL} or V_{IH}	3.0	3.4		3.0		V
			V_{CC} = 4.5V; I_{OH} = -32mA; V_I = V_{IL} or V_{IH}	2.0	2.4		2.0		V
		. 1.	V_{CC} = 4.5V; I_{OL} = 5mA; V_I = V_{IL} or V_{IH}		0.32	0.55		0.55	V
V _{OL}	Low-level output	it voltage	V_{CC} = 4.5V; I_{OL} = 12mA; V_I = V_{IL} or V_{IH}		0.5	0.8		0.8	V
	Input leakage	Control pins	V _{CC} = 5.5V; V _I = GND or 5.5V		±0.01	±1.0		±1.0	μA
I _I	current	Data pins	V_{CC} = 5.5V; V_I = GND or 5.5V		±5	±100		±100	μΑ
I _{OFF}	Power-off leakage current		$V_{CC} = 0.0V$; V_{I} or $V_{O} \le 4.5V$		±5.0	±100		±100	μΑ
I _{PU} /I _{PD}	Power-up/down 3-State output current ³		$V_{CC} = 2.1V; V_0 = 0.5V; V_I = GND \text{ or } V_{CC};$ V _{OE} = Don't care		±5.0	±50		±50	μΑ
I _{IH} + I _{OZH}	3-State output H	High current	V_{CC} = 5.5V; V_O = 2.7V; V_I = V_{IL} or V_{IH}		5.0	50		50	μΑ
I _{IL} + I _{OZL}	3-State output L	ow current	V_{CC} = 5.5V; V_O = 0.5V; V_I = V_{IL} or V_{IH}		-5.0	-50		-50	μΑ
I _{CEX}	Output high lea	kage current	V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = GND or V_{CC}		5.0	50		50	μΑ
Ι _Ο	Output current ¹		V _{CC} = 5.5V; V _O = 2.5V	-40	-100	-180	-40	-180	mA
I _{CCH}			V_{CC} = 5.5V; Outputs High, V_{I} = GND or V_{CC}		50	250		250	μΑ
I _{CCL}	Quiescent supply current		V_{CC} = 5.5V; Outputs Low, V_I = GND or V_{CC}		24	30		30	mA
I _{CCZ}			V_{CC} = 5.5V; Outputs 3-State; V _I = GND or V _{CC}		50	250		250	μA
	Additional supply current per input pin ²		Outputs enabled, one input at 3.4V, other inputs at V_CC or GND; V_CC = 5.5V		0.5	1.5		1.5	mA
ΔI_{CC}			Outputs 3-State, one data input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V		50	250		250	μA
			Outputs 3-State, one enable input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V		0.5	1.5		1.5	mA

NOTES:

1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

2. This is the increase in supply current for each input at 3.4V. 3. This parameter is valid for any V_{CC} between 0V and 2.1V with a transition time of up to 10msec. From V_{CC} = 2.1V to V_{CC} = 5V \pm 10%, a transition time of up to 100µsec is permitted.

Product specification

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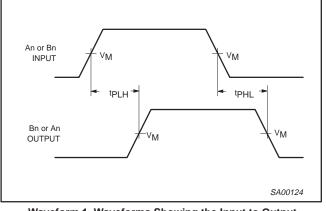
AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$, $R_L = 500 \Omega$

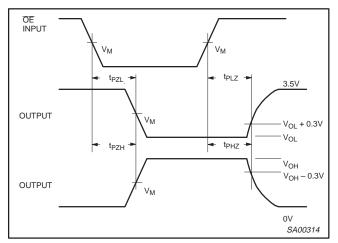
					LIMIT	S		
SYMBOL	PARAMETER	WAVEFORM	T _é V	_{mb} = +25° _{CC} = +5.0	C V	$T_{amb} = -40^{\circ}$ $V_{CC} = +5.$	°C to +85°C .0V ±0.5V	UNIT
			Min	Тур	Мах	Min	Max	
t _{PLH} t _{PHL}	Propagation delay An to Bn or Bn to An	1	1.0 1.0	2.8 3.9	4.2 5.0	1.0 1.0	4.7 5.4	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.3 3.0	3.5 5.5	4.6 7.0	1.3 3.0	5.5 7.8	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low Level	2	1.5 1.0	4.0 3.4	5.4 4.6	1.5 1.0	6.3 5.0	ns

AC WAVEFORMS

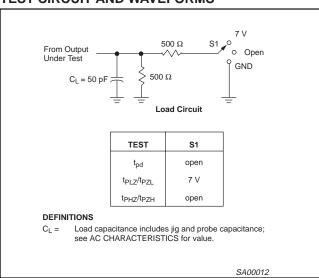
 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$



Waveform 1. Waveforms Showing the Input to Output Propagation Delays



Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

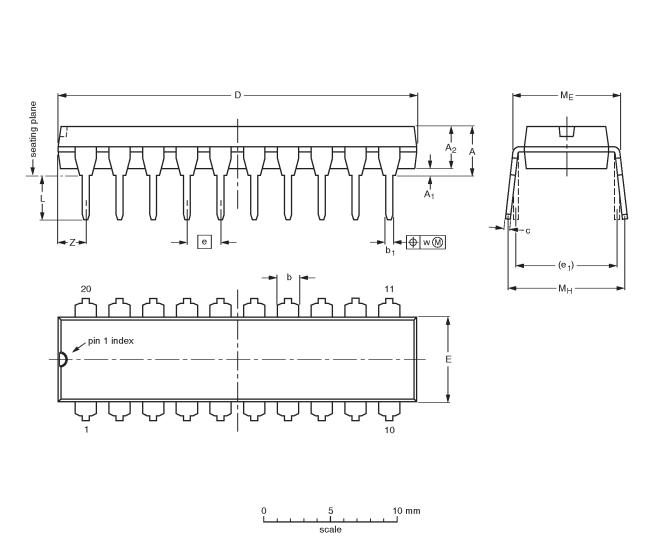


TEST CIRCUIT AND WAVEFORMS

74ABT2245

DIP20: plastic dual in-line package; 20 leads (300 mil)

Octal transceiver with direction pin and 30Ω series termination resistors (3-State)



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	р ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note

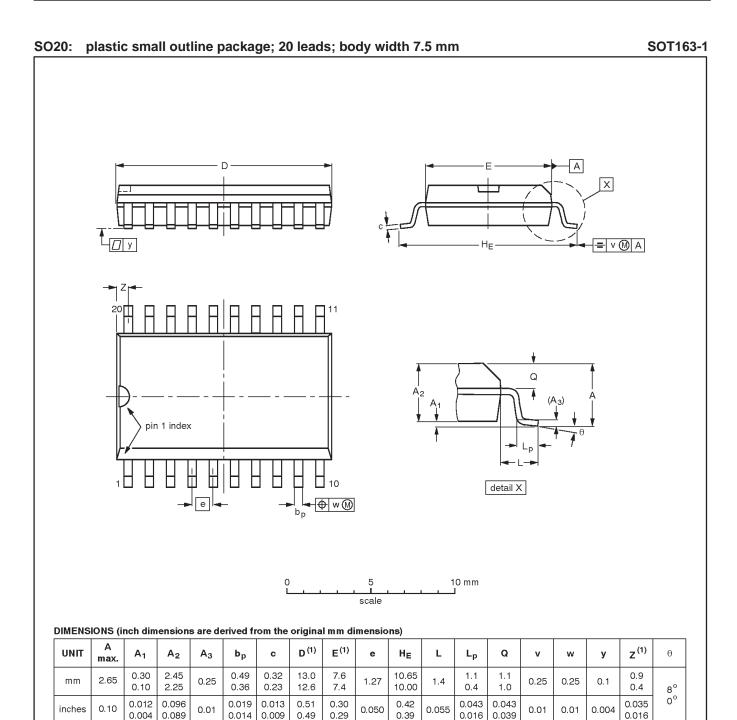
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFEF	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT146-1			SC603		-92-11-17 95-05-24

SOT146-1

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Product specification



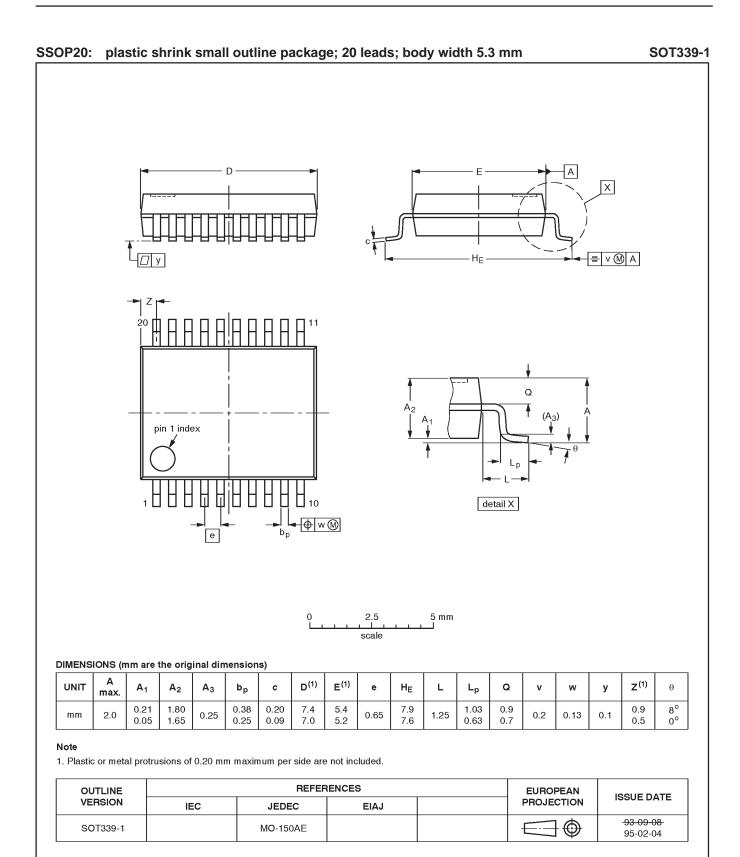
Ν	ot	e

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

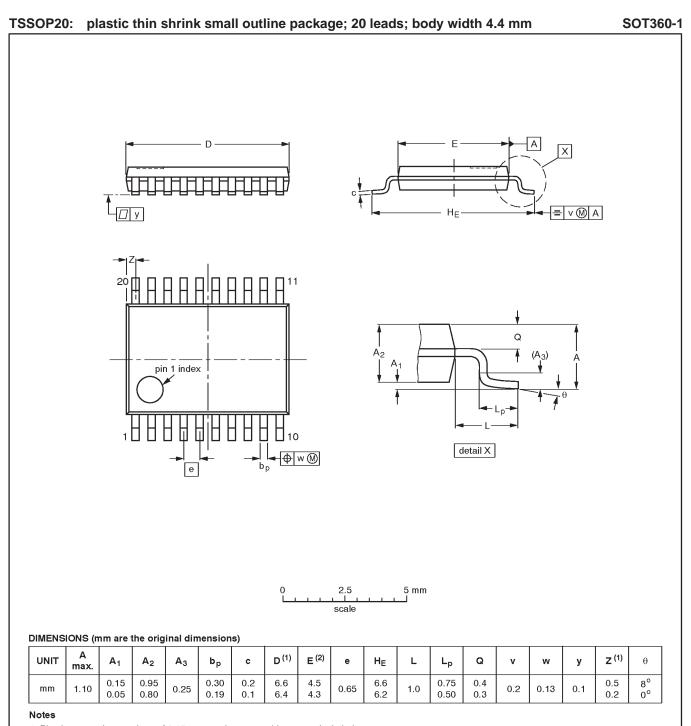
OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1350E DATE
SOT163-1	075E04	MS-013AC				-92-11-17 95-01-24

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Product specification



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1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
		IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
	SOT360-1		MO-153AC				-93-06-16 95-02-04

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NOTES

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Data sheet status

Data sheet status	Product status	Definition ^[1]	
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.	
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.	
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.	

[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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